Thyristor Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.646 inches

**Mounting Facility Quantity:** 

1

## Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Overall Width Across Flats:

0.562 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

700.0 forward voltage, peak and 700.0 nonrepetitive peak reverse voltage, peak total value and 600.0 repetitive peak reverse voltage, peak total value

# **Current Rating Per Characteristic:**

250.00 amperes forward current, average preset and 40.00 amperes forward current, average megahertz and 25.00 amperes forward current, average

#### **Power Rating Per Characteristic:**

40.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector universal

#### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

#### **Test Data Document:**

49956-482824 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

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